FAIRCHILD

SEMICONDUCTOR IM

FDS9431A_F085

P-Channel 2.5V Specified MOSFET

General Description

This P-Channel 2.5V specified MOSFET is produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

Applications

- DC/DC converter
- Power management
- Load switch
- Battery protection

February 2010

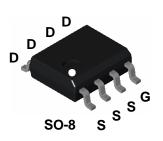
Features

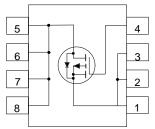
• -3.5 A, -20 V. $R_{DS(ON)} = 0.130 \ \Omega \ @ V_{GS} = -4.5 \ V$ $R_{DS(ON)} = 0.180 \ \Omega \ @ V_{GS} = -2.5 \ V.$

- Fast switching speed.
- High density cell design for extremely low R_{DS(ON)}.
- High power and current handling capability.
- Qualified to AEC Q101
- RoHS Compliant



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Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
ID	Drain Current - Continuous	(Note 1a)	-3.5	A
	- Pulsed		-18	
PD	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.2	
		(Note 1c)	1.0	
TJ, T _{stg}	Operating and Storage Junction Temperat	ure Range	-55 to +150	°C

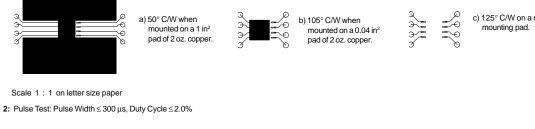
Thermal Characteristics

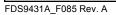
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

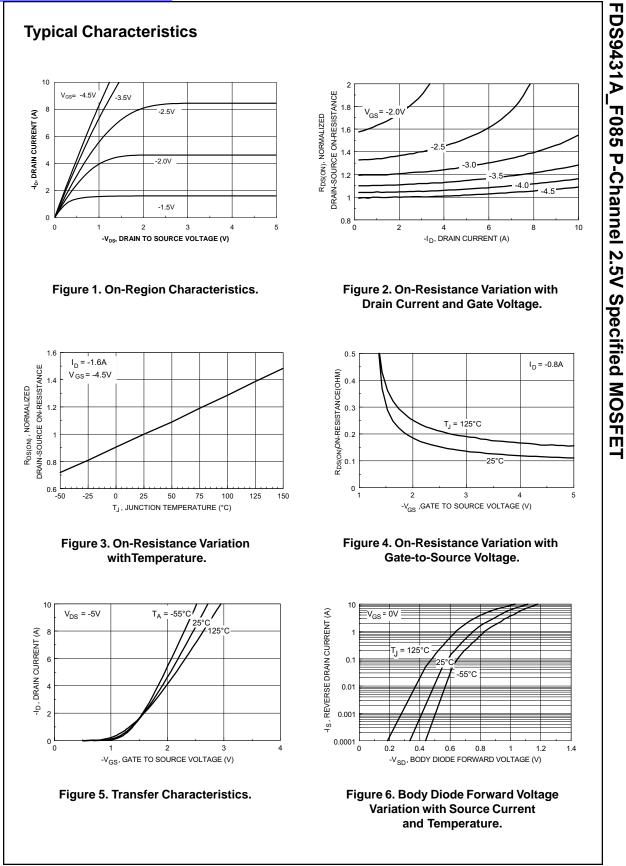
Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS9431A	FDS9431A_F085	13"	12mm	2500 units

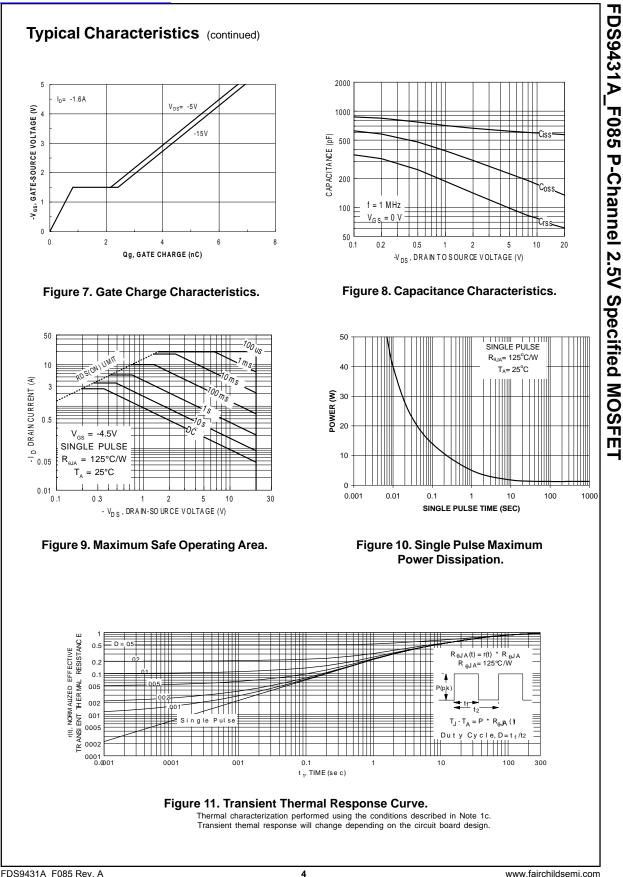
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	I_D = -250 µA,Referenced to 25°C		-28		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = -16$ V, $V_{GS} = 0$ V			-1	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = 8 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-0.4	-0.6	-1	V
$\Delta V_{GS(th)}$ ΔT_{J}	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A,Referenced to 25°C		2		mV/°C
R _{DS(on)}	Static Drain-Source	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$		0.110	0.130	Ω
- (-)	On-Resistance	$V_{GS} = -2.5 \text{ V}, I_D = -3.0 \text{ A}$		0.140	0.180	Ω
		V _{GS} = -4.5 V, I _D = -3.5 A T _{.I} =125°C		0.155	0.220	Ω
I _{D(on)}	On-State Drain Current	V _{GS} = -4.5 V, V _{DS} =-5 V	-10			A
g FS	Forward Transconductance	V _{DS} = -5 V, I _D = -3.5 A		6.5		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -10 V, V_{GS} = 0 V,$		405		pF
Coss	Output Capacitance	f = 1.0 MHz		170		pF
Crss	Reverse Transfer Capacitance	-		45		pF
Switchir	ng Characteristics (Note 2)		1			-
t _{d(on)}	Turn-On Delay Time	V _{DD} = -5 V, I _D = -1 A,		6.5	13	ns
tr	Turn-On Rise Time	$V_{GS} = -4.5$ V, $R_{GEN} = 6 \Omega$		20	35	ns
t _{d(off)}	Turn-Off Delay Time	-		31	50	ns
t _f	Turn-Off Fall Time	-		21	35	ns
	Total Gate Charge	V _{DS} = -5 V, I _D = -3.5 A,		6	8.5	nC
(Ja	Gate-Source Charge	$V_{GS} = -4.5 V$		0.8	0.0	nC
0			I	1 0.0		-
Q _{gs}	ů – ř	-		13		<u>μ</u> ης.
Q _{gs} Q _{gd}	Gate-Drain Charge			1.3		nC
Q _{gs} Q _{gd} Drain-Sc	Gate-Drain Charge			1.3	-2.1	nC A
	Gate-Drain Charge			-0.7	-2.1	A







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F-PFS™	FUwer-SPIN!"	GENERAL	

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No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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